

/ Descriptions

TO-252 NPN Silicon NPN transistor in a TO-252 Plastic Package.

/ Features

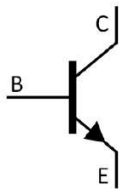
f_T

Low $V_{CE(sat)}$, high current and high f_T , excellent linearity of h_{FE} , fast switching time.

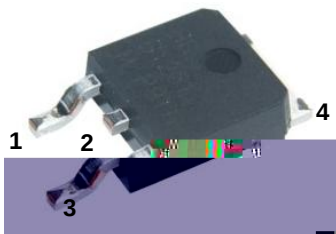
/ Applications

Relay drivers, high-speed inverters, general high-current switching applications.

/ Equivalent Circuit



/ Pinning



PIN1 Base PIN 2,4 Collector PIN 3 Emitter

/ h_{FE} Classifications & Marking

h_{FE} Classifications Symbol	Q	R	S	T
h_{FE} Range	70 140	100 200	140 280	200 400

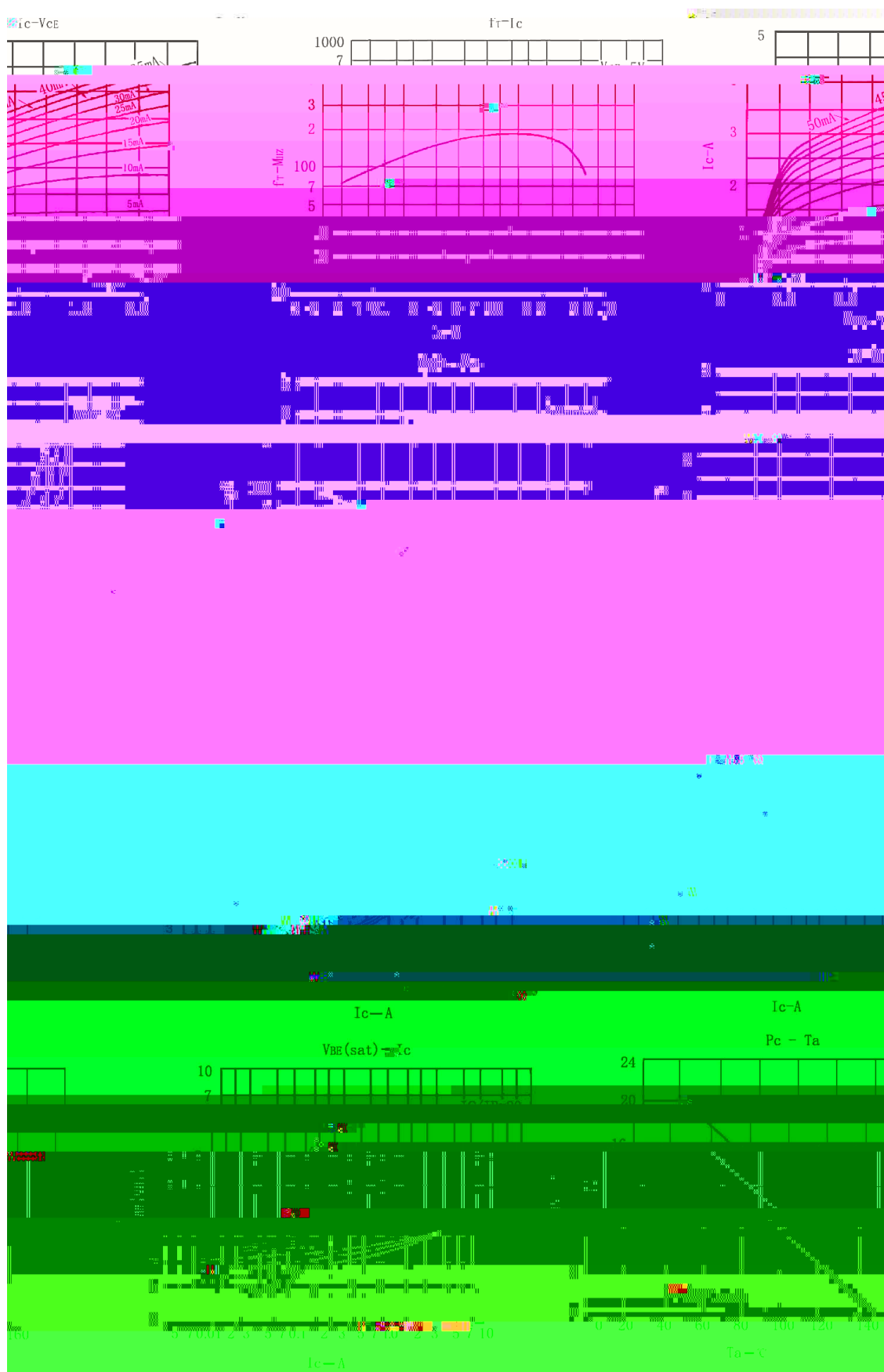
/ Absolute Maximum Ratings(Ta=25)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	60	V
Collector to Emitter Voltage	V_{CEO}	50	V
Emitter to Base Voltage	V_{EBO}	6	V
Collector Current - Continuous	I_C	5	A
Collector Current – Continuous(Pulse)	I_{CP}	8	A
Collector Power Dissipation	P_C	1.0	W
Collector Power Dissipation	$P_C(T_c=25)$	20	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

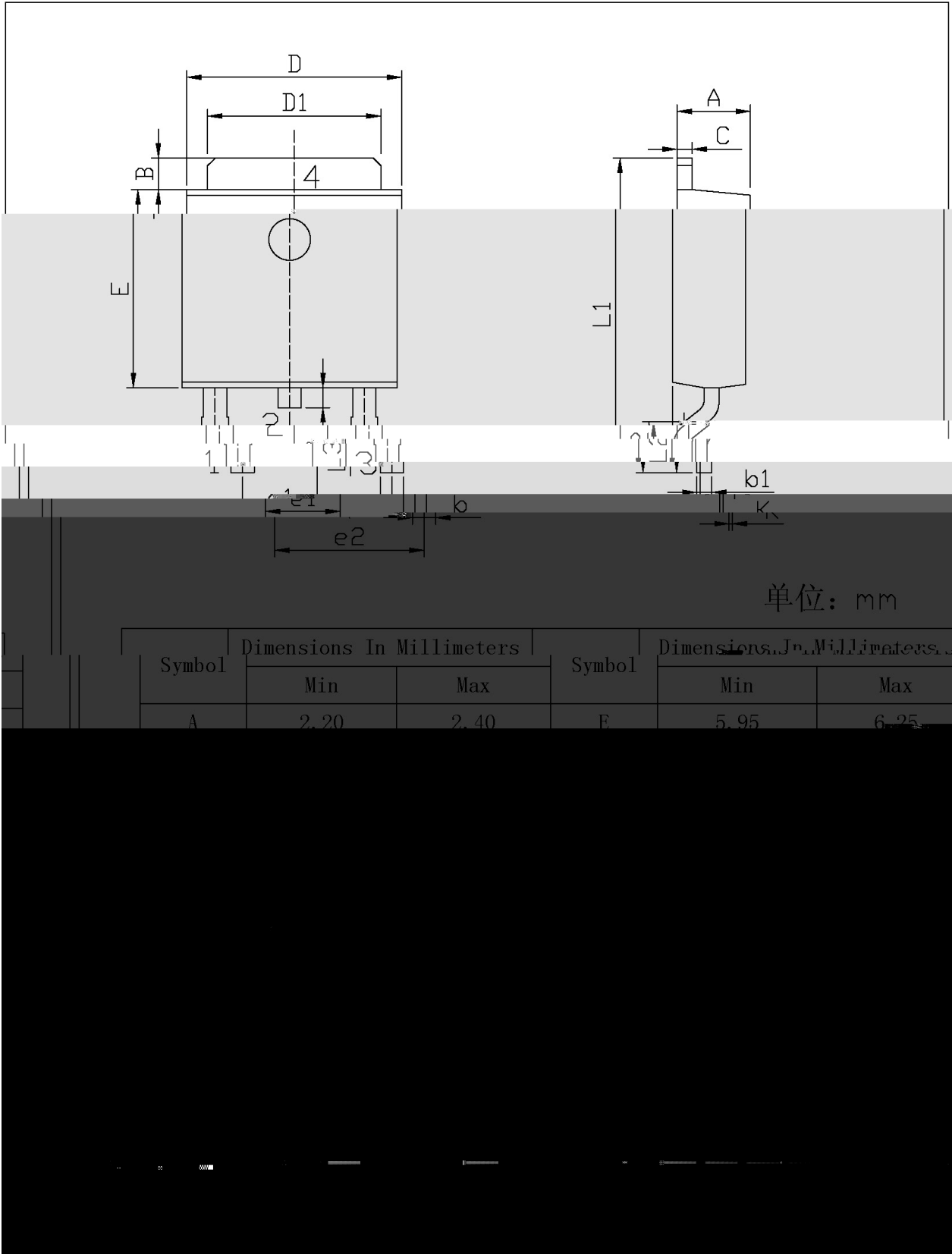
/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Base Breakdown Voltage	V_{CBO}	$I_C=10\mu A$ $I_E=0$	60			V
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C=1.0mA$ $R_{BE}=\infty$	50			V
Emitter to Base Breakdown Voltage	V_{EBO}	$I_E=10\mu A$ $I_C=0$	6			V
Collector Cut-Off Current	I_{CBO}	$V_{CB}=40V$ $I_E=0$			1.0	μA
Emitter Cut-Off Current	I_{EBO}	$V_{EB}=4.0V$ $I_C=0$			1.0	μA
DC Current Gain	$h_{FE(1)}$	$V_{CE}=2.0V$ $I_C=0.5A$	70		400	
	$h_{FE(2)}$	$V_{CE}=2.0V$ $I_C=4.0A$	35			
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=3.0A$ $I_B=0.15A$		0.22	0.4	V
Base to Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=3.0A$ $I_B=0.15A$		0.95	1.3	V
Transition Frequency	f_T	$V_{CE}=5.0V$ $I_C=1.0A$		180		MHz
Collector output capacitance	C_{ob}	$V_{CB}=10V$ $f=1.0MHz$		40		pF
Turn-On Time	t_{on}	$I_C=10I_{B1}=-10I_{B2}=2.0A$		50		ns
Storage Time	t_{stg}			500		ns
Fall Time	t_f			20		ns

/ Electrical Characteristic Curve

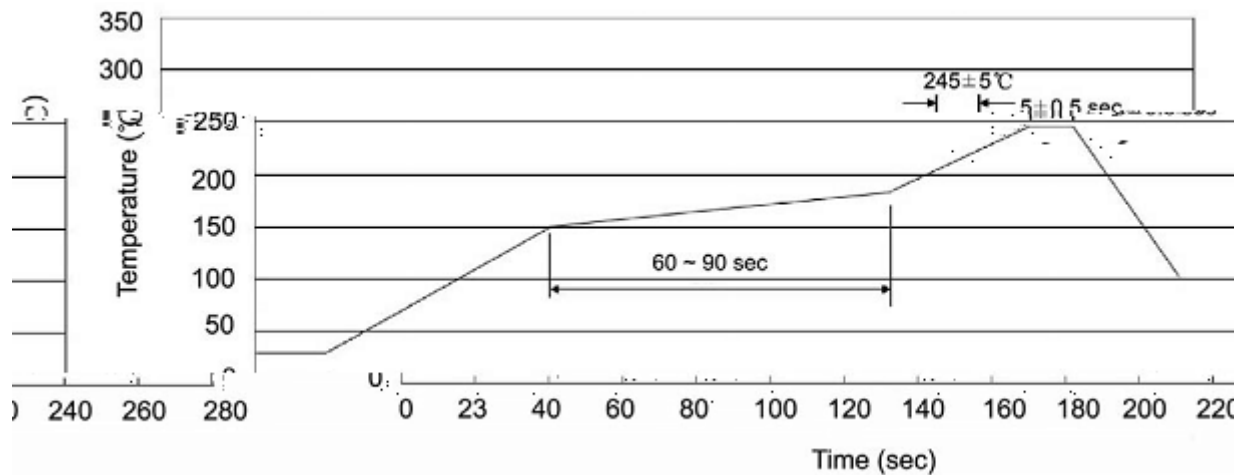


/ Package Dimensions



2SD1803

() / **Temperature Profile for IR Reflow Soldering(Pb-Free)**



Note:

- | | | | | | |
|---|-------|-----|-----------|--------|---|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 245±5 | | 5±0.5sec; | | 2.Peak Temp.:245±5 , Duration:5±0.5sec. |
| 3 | | 2 | 10 | /sec. | 3. Cooling Speed: 2~10 /sec. |

/ **Resistance to Soldering Heat Test Conditions**

260±5 10±1 sec. Temp.:260±5 Time:10±1 sec

/ **Packaging SPEC.**

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	只 卷盘	卷盘 盒	只 盒	盒 箱	只 箱		盒	箱

/ TUBE

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	只 套管	套管 盒	只 盒	盒 箱	只 箱	套管	盒	箱

/ **Notices**